

ABSOLUTE MAXIMUM RATINGS at $T_A = 25^{\circ}C$

Logic Supply Voltage, V_{DD}......**15 V** Driver Supply Voltage, V_{BB}......**60 V** Continuous Output Current Range.

I_{OUT}.....-40 to +15 mA

Input Voltage Range,

V_{IN} -0.3 V to V_{DD} + 0.3 V

Package Power Dissipation, PD (UCQ5812AF)..... 3.12 W*

(UCQ5812EPF)1.84 W†

Operating Temperature Range,

T_A-40°C to +85°C Storage Temperature Range,

T_S--55°C to +150°C

- * Derate at rate of 22 mW/°C above T_A = +25°C
- † Derate at rate of 15 mW/°C above T_A = +25°C

Caution: Allegro CMOS devices have input static protection but are susceptible to damage when exposed to extremely high static electrical charges.

Note that the UCQ5812AF (dual in-line package) and UCQ5812EPF (PLCC package) are electrically identical and share a common pin number assignment.

The UCQ5812AF/EPF combine a 20-bit CMOS shift register, data latches, and control circuitry with high-voltage bipolar source drivers and active DMOS pull-downs for reduced supply current requirements. Although designed primarily for vacuum-fluorescent displays, the high-voltage, highcurrent outputs also allow them to be used in other peripheral power driver applications.

The CMOS shift register and latches allow direct interfacing with microprocessor-based systems. With a 5 V supply, they will operate to at least 3.3 MHz. At 12 V, higher speeds are possible. Especially useful for inter-digit blanking, the BLANKING input disables the output source drives and turns on the DMOS sink drivers. Use with TTL may require the use of appropriate pull-up resistors to ensure an input logic high.

A CMOS serial data output enables cascade connections in applications requiring additional drive lines. Similar devices are available as the UCQ5810AF/LWF (10 bits), UCQ5811A (12 bits), and UCQ5818AF/EPF (32 bits).

The output source drivers are high-voltage PNP-NPN Darlingtons with a minimum breakdown of 60 V and are capable of sourcing up to 40 mA. The DMOS active pull-downs are capable of sinking up to 15 mA.

The UCQ5812AF is supplied in a 28-pin dual in-line plastic package with 0.600" (15.24 mm) row spacing. For surface mounting, the UCQ5812EPF is furnished in 28-lead plastic chip carrier (quad pack) with 0.050"(1.22 mm) centers. Copper lead-frames, reduced supply current requirements and lower output saturation voltages, allow continuous operation, with all outputs sourcing 25 mA, of the UCQ5812AF over the operating temperature range, and the UCQ5812EPF up to +75°C.

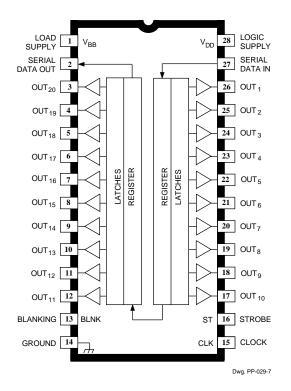
FEATURES

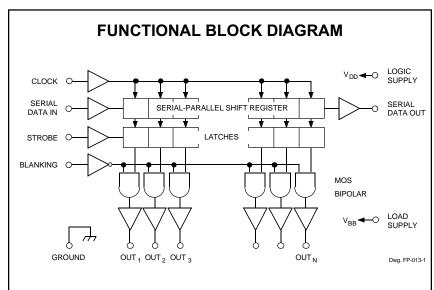
- High-Speed Source Drivers
- 60 V Source Outputs
- To 3.3 MHz Data Input Rate
- Low-Output Saturation Voltages
- Low-Power CMOS Logic and Latches
- Active DMOS Pull-Downs
- Reduced Supply Current Requirements
- Improved Replacement for TL5812

Always order by complete part number, e.g., | UCQ5812AF |.

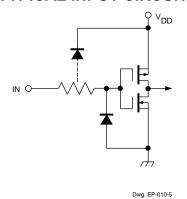


UCQ5812AF

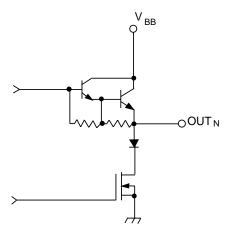




TYPICAL INPUT CIRCUIT



TYPICAL OUTPUT DRIVER



Dwg. No. A-14,219

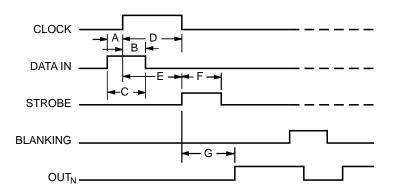


ELECTRICAL CHARACTERISTICS over operating temperature range, at V_{BB} = 60 V (unless otherwise noted).

| | | | Limits @ V _{DD} = 5 V | | Limits | | | | |
|--------------------------|---------------------|--|--------------------------------|-------|--------|------|------|------|-------|
| Characteristic | Symbol | Test Conditions | MIn. | Тур. | Max. | Min. | Тур. | Max. | Units |
| Output Leakage Current | I _{CEX} | $V_{OUT} = 0 \text{ V}, T_A = +70^{\circ}\text{C}$ | _ | -5.0 | -15 | _ | -5.0 | -15 | μΑ |
| Output Voltage | V _{OUT(1)} | I _{OUT} = -25 mA, V _{BB} = 60 V | 58 | 58.5 | _ | 58 | 58.5 | _ | V |
| | V _{OUT(0)} | I _{OUT} = 1 mA | _ | 2.0 | 3.0 | _ | _ | _ | V |
| | | I _{OUT} = 2 mA | _ | _ | _ | _ | 2.0 | 3.5 | V |
| Output Pull-Down Current | I _{OUT(0)} | $V_{OUT} = 5 \text{ V to } V_{BB}$ | 2.0 | 3.5 | _ | _ | _ | _ | mA |
| | | $V_{OUT} = 20 \text{ V to } V_{BB}$ | _ | _ | _ | 8.0 | 13 | _ | mA |
| Input Voltage | V _{IN(1)} | | 3.5 | _ | 5.3 | 10.5 | _ | 12.3 | V |
| | V _{IN(0)} | | -0.3 | | +0.8 | -0.3 | _ | +0.8 | V |
| Input Current | I _{IN(1)} | $V_{IN} = V_{DD}$ | _ | 0.05 | 0.5 | | 0.1 | 1.0 | μΑ |
| | I _{IN(0)} | V _{IN} = 0.8 V | _ | -0.05 | -0.5 | _ | -0.1 | -1.0 | μΑ |
| Serial Data | V _{OUT(1)} | I _{OUT} = -200 μA | 4.5 | 4.7 | _ | 11.7 | 11.8 | _ | V |
| | V _{OUT(0)} | I _{OUT} = 200 μA | _ | 200 | 250 | _ | 100 | 200 | mV |
| Maximum Clock Frequency | f _{clk} | | 3.3* | _ | _ | _ | _ | _ | MHz |
| Supply Current | I _{DD(1)} | All Outputs High | _ | 100 | 300 | _ | 200 | 500 | μΑ |
| | I _{DD(0)} | All Outputs Low | _ | 100 | 300 | _ | 200 | 500 | μΑ |
| | I _{BB(1)} | Outputs High, No Load | _ | 1.5 | 4.0 | _ | 1.5 | 4.0 | mA |
| | I _{BB(0)} | Outputs Low | _ | 10 | 100 | _ | 10 | 100 | μΑ |
| Blanking to Output Delay | t _{PHL} | C _L = 30 pF, 50% to 50% | _ | 2000 | _ | _ | 1000 | _ | ns |
| | t _{PLH} | C _L = 30 pF, 50% to 50% | _ | 1000 | _ | _ | 850 | _ | ns |
| Output Fall Time | t _f | C _L = 30 pF, 90% to 10% | _ | 1450 | _ | _ | 650 | _ | ns |
| Output Rise Time | t _r | C _L = 30 pF, 10% to 90% | _ | 650 | _ | | 700 | _ | ns |

Negative current is defined as coming out of (sourcing) the specified device pin.

^{*} Operation at a clock frequency greater than the specified minimum value is possible but not warranteed.



Dwg. No. 12,649A

TIMING REQUIREMENTS

 $(T_A = +25^{\circ}C, V_{DD} = 5 \text{ V}, \text{Logic Levels are } V_{DD} \text{ and Ground})$

| Α. | Minimum Data Active Time Before Clock Pulse (Data Set-Up Time) | . 75 ns |
|----|--|---------|
| В. | Minimum Data Active Time After Clock Pulse (Data Hold Time) | . 75 ns |
| C. | Minimum Data Pulse Width | 150 ns |
| D. | Minimum Clock Pulse Width | 150 ns |
| E. | Minimum Time Between Clock Activation and Strobe | 300 ns |
| F. | Minimum Strobe Pulse Width | 100 ns |
| G. | Typical Time Between Strobe Activation and | |
| | Output Transistion | 500 ns |

Timing is representative of a 3.3 MHz clock. Higher speeds may be attainable with increased supply voltage; operation at high temperatures will reduce the specified maximum clock frequency.

Serial Data present at the input is transferred to the shift register on the logic "0" to logic "1" transition of the CLOCK input pulse. On succeeding CLOCK pulses, the registers shift data information towards the SERIAL DATA OUT-PUT. The SERIAL DATA must appear at the input prior to the rising edge of the CLOCK input waveform.

Information present at any register is transferred to the respective latch when the STROBE is high (serial-to-parallel conversion). The latches will continue to accept new data as long as the STROBE is held high. Applications where the latches are bypassed (STROBE tied high) will require that the BLANKING input be high during serial data entry.

When the BLANKING input is high, the output source drivers are disabled (OFF); the DMOS sink drivers are ON, the information stored in the latches is not affected by the BLANKING input. With the BLANKING input low, the outputs are controlled by the state of their respective latches.

TRUTH TABLE

| Serial | | Shif | ft Re | gist | er C | ontents | Serial | Latch Co | | | onte | nts | | Output Contents | | | | | | |
|--------|-------|----------------|----------------|----------------|------|---------------------------------|------------------|----------|----------------|----------------|----------------|-----|---------------------------------|-----------------|----------------|----------------|----------------|-----|------------------|----------------|
| Data | Clock | | | | | | | Strobe | | | | | | 1 | | | | | | |
| Input | Input | I ₁ | l ₂ | l ₃ | ••• | I _{N-1} I _N | Output | Input | I ₁ | l ₂ | l ₃ | ••• | I _{N-1} I _N | Blanking | I ₁ | l ₂ | l ₃ | ••• | I _{N-1} | I _N |
| Н | 」」 | Н | R_1 | R_2 | | $R_{N-2}R_{N-1}$ | R _{N-1} | | | | | | | | | | | | | |
| L | | L | R_1 | R_2 | | $R_{N-2}R_{N-1}$ | R _{N-1} | | | | | | | | | | | | | |
| Х | 1 | R ₁ | R_2 | R_3 | | $R_{N-1}R_{N}$ | R _N | | | | | | | | | | | | | |
| | | Χ | Χ | Χ | | ХХ | Х | L | R ₁ | R_2 | R_3 | | R _{N-1} R _N | | | | | | | |
| | | P ₁ | P_2 | P_3 | | $P_{N-1} P_N$ | P _N | Н | P ₁ | P ₂ | P_3 | | P_{N-1} P_{N} | L | P ₁ | P_2 | P_3 | | P _{N1} | P_N |
| | | | | | | | | | X | Χ | Χ | | ХХ | Н | L | L | L | | L | L |

L = Low Logic Level H = High Logic Level

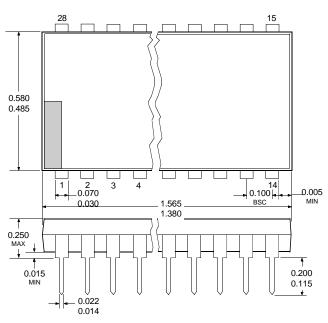
X = Irrelevant

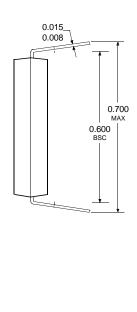
P = Present State R = Previous State



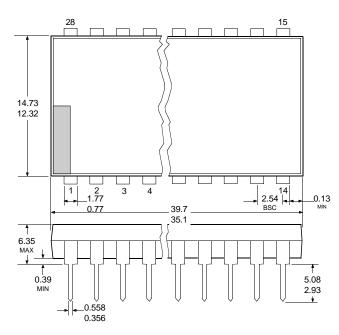
UCQ5812AF

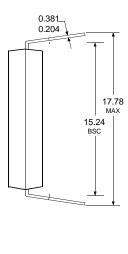
Dimensions in Inches (controlling dimensions)





Dimensions in Millimeters (for reference only)



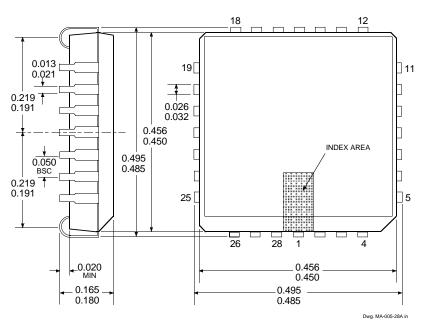


Dwn MA-003-28 in

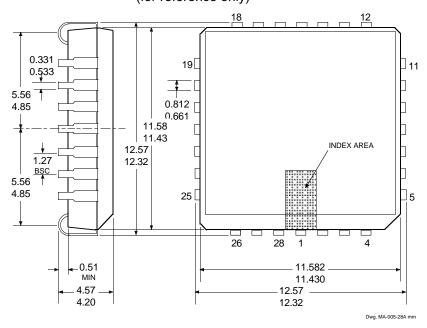
- NOTES: 1. Exact body and lead configuration at vendor's option within limits shown.
 - 2. Lead spacing tolerance is non-cumulative.
 - 3. Lead thickness is measured at seating plane or below.
 - 4. Supplied in standard sticks/tubes of 12 devices.

UCN5812EPF

Dimensions in Inches (controlling dimensions)



Dimensions in Millimeters (for reference only)



NOTES: 1. Exact body and lead configuration at vendor's option within limits shown.

- 2. Lead spacing tolerance is non-cumulative.
- 3. Supplied in standard sticks/tubes of 38 devices or add "TR" to part number for tape and reel.



The products described here are manufactured under one or more U.S. patents or U.S. patents pending.

Allegro MicroSystems, Inc. reserves the right to make, from time to time, such departures from the detail specifications as may be required to permit improvements in the performance, reliability, or manufacturability of its products. Before placing an order, the user is cautioned to verify that the information being relied upon is current.

Allegro products are not authorized for use as critical components in life-support devices or systems without express written approval.

The information included herein is believed to be accurate and reliable. However, Allegro MicroSystems, Inc. assumes no responsibility for its use; nor for any infringement of patents or other rights of third parties which may result from its use.

POWER INTERFACE DRIVERS

| Function | Output l | Ratings* | Part Number [†] | | | | | | |
|--|----------------|----------|--------------------------|--|--|--|--|--|--|
| SERIAL-INPUT LATCHED DRIVERS | | | | | | | | | |
| 8-Bit (saturated drivers) | -120 mA | 50 V‡ | 5895 | | | | | | |
| 8-Bit | 350 mA | 50 V | 5821 | | | | | | |
| 8-Bit | 350 mA | 80 V | 5822 | | | | | | |
| 8-Bit | 350 mA | 50 V‡ | 5841 | | | | | | |
| 8-Bit | 350 mA | 80 V‡ | 5842 | | | | | | |
| 8-Bit (constant-current LED driver) | 75 mA | 17 V | 6275 | | | | | | |
| 8-Bit (constant-current LED driver) | 120 mA | 24 V | 6277 | | | | | | |
| 8-Bit (DMOS drivers) | 250 mA | 50 V | 6595 | | | | | | |
| 8-Bit (DMOS drivers) | 350 mA | 50 V‡ | 6A595 | | | | | | |
| 8-Bit (DMOS drivers) | 100 mA | 50 V | 6B595 | | | | | | |
| 10-Bit (active pull-downs) | -25 mA | 60 V | 5810-F and 6810 | | | | | | |
| 12-Bit (active pull-downs) | -25 mA | 60 V | 5811 | | | | | | |
| 16-Bit (constant-current LED driver) | 75 mA | 17 V | 6276 | | | | | | |
| 20-Bit (active pull-downs) | -25 mA | 60 V | 5812-F and 6812 | | | | | | |
| 32-Bit (active pull-downs) | -25 mA | 60 V | 5818-F and 6818 | | | | | | |
| 32-Bit | 100 mA | 30 V | 5833 | | | | | | |
| 32-Bit (saturated drivers) | 100 mA | 40 V | 5832 | | | | | | |
| PARALLEI | -INPUT LATCHED | DRIVERS | | | | | | | |
| 4-Bit | 350 mA | 50 V‡ | 5800 | | | | | | |
| 8-Bit | -25 mA | 60 V | 5815 | | | | | | |
| 8-Bit | 350 mA | 50 V‡ | 5801 | | | | | | |
| 8-Bit (DMOS drivers) | 100 mA | 50 V | 6B273 | | | | | | |
| 8-Bit (DMOS drivers) | 250 mA | 50 V | 6273 | | | | | | |
| SPECI | AL-PURPOSE DEV | ICES | | | | | | | |
| Unipolar Stepper Motor Translator/Driver | 1.25 A | 50 V‡ | 5804 | | | | | | |
| Addressable 8-Bit Decoder/DMOS Driver | 250 mA | 50 V | 6259 | | | | | | |
| Addressable 8-Bit Decoder/DMOS Driver | 350 mA | 50 V‡ | 6A259 | | | | | | |
| Addressable 8-Bit Decoder/DMOS Driver | 100 mA | 50 V | 6B259 | | | | | | |
| Addressable 28-Line Decoder/Driver | 450 mA | 30 V | 6817 | | | | | | |

^{*} Current is maximum specified test condition, voltage is maximum rating. See specification for sustaining voltage limits. Negative current is defined as coming out of (sourcing) the output.

[‡] Internal transient-suppression diodes included for inductive-load protection.



[†] Complete part number includes additional characters to indicate operating temperature range and package style.